

## CD4009M/CD4009C Hex Buffers (Inverting) CD4010M/CD4010C Hex Buffers (Non-Inverting)

### General Description

These hex buffers are monolithic complementary MOS (CMOS) integrated circuits. The N- and P-channel enhancement mode transistors provide a symmetrical circuit with output swings essentially equal to the supply voltage. This results in high noise immunity over a wide supply voltage range. No DC power other than that caused by leakage current is consumed during static conditions. All inputs are protected against static discharge. These gates may be used as hex buffers, CMOS to DTL or TTL interface or as CMOS current drivers. Conversion ranges are from 3V to 15V providing  $V_{CC} \leq V_{DD}$ .

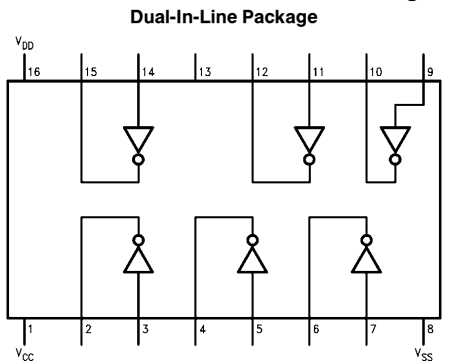
### Features

- Wide supply voltage range 3.0V to 15V
- Low power 100 nW (typ.)
- High noise immunity 0.45  $V_{DD}$  (typ.)
- High current sinking capability 8 mA (min.) at  $V_O = 0.5V$  and  $V_{DD} = 10V$

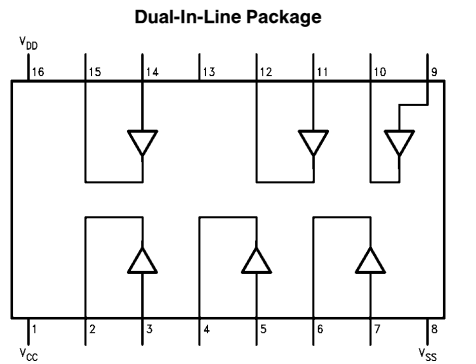
### Applications

- Automotive
- Data terminals
- Instrumentation
- Medical electronics
- Alarm system
- Industrial controls
- Remote metering
- Computers

### Schematic and Connection Diagrams



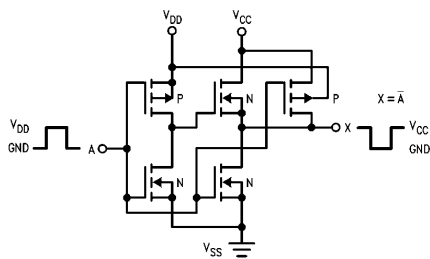
TL/F/5945-2



TL/F/5945-4

Order Number CD4009 or CD4010

#### CD4009M/CD4009C

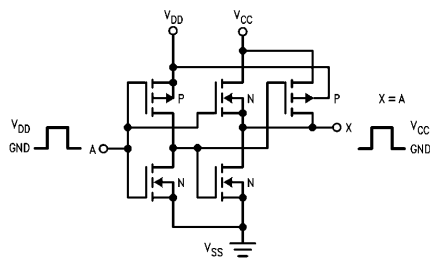


Hex COS/MOS to DTL or TTL converter (non-inverting).

Connect  $V_{CC}$  to DTL or TTL supply.  
Connect  $V_{DD}$  to COS/MOS supply.

TL/F/5945-1

#### CD4010M/CD4010C



Hex COS/MOS to DTL or TTL converter (inverting).

Connect  $V_{CC}$  to DTL or TTL supply.  
Connect  $V_{DD}$  to COS/MOS supply.

TL/F/5945-3

CD4009M/CD4009C Hex Buffers (Inverting)  
CD4010M/CD4010C Hex Buffers (Non-Inverting)

## Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Voltage at Any Pin (Note 1)  $V_{SS} - 0.3V$  to  $V_{SS} + 15.5V$

Operating Temperature Range  
 CD40XXM  $-55^{\circ}C$  to  $+125^{\circ}C$   
 CD40XXC  $-45^{\circ}C$  to  $+85^{\circ}C$

Storage Temperature Range ( $T_S$ )  $-65^{\circ}C$  to  $+150^{\circ}C$

Power Dissipation ( $P_D$ )  
 Dual-In-Line 700 mW  
 Small Outline 500 mW

Lead Temperature ( $T_L$ )  
 (Soldering, 10 seconds)  $260^{\circ}C$

Operating Range ( $V_{DD}$ )  $V_{SS} + 3V$  to  $V_{SS} + 15V$

## DC Electrical Characteristics

Symbol	Characteristics	Test Conditions (Volts)		Limits												Units	
				CD40XXM						CD40XXC							
				$-55^{\circ}C$		$+25^{\circ}C$		$+125^{\circ}C$		$-40^{\circ}C$		$+25^{\circ}C$		$+85^{\circ}C$			
$V_O$	$V_{DD}$	Min	Max	Min	Typ	Max	Min	Max	Min	Max	Min	Typ	Max	Min	Max		
$I_{CC}$	Quiescent Device Current	5	5	0.3	0.3	0.01	0.3	0.01	0.5	20	3	0.03	3	0.05	5	42	$\mu A$
$P_D$	Quiescent Device Dissipation/Package	5	10	1.5	5	0.05	1.5	0.1	5	100	15	0.15	15	0.5	50	210	$\mu W$
$V_{OL}$	Output Voltage Low Level	5	10	0.01	0.01	0	0.01	0	0.01	0.05	0.01	0	0.01	0	0.01	0.05	V
$V_{OH}$	Output Voltage High Level	5	10	4.99	9.99	4.99	9.99	5	10	4.95	9.99	4.99	9.99	5	10	4.95	V
$V_{NL}$	Noise Immunity (All Inputs)																V
	CD4009M	$V_O \geq 4.0$	5	1	1	2.25	0.9	1	2.25	0.9	1	2.25	0.9	1	2.25	0.9	V
		$V_O \geq 8.0$	10	2	2	4.5	1.9	2	4.5	1.9	2	4.5	1.9	2	4.5	1.9	V
	CD4010M	$V_O \geq 1.5$	5	1.6	1.5	2.25	1.4	1.6	2.25	1.4	1.6	2.25	1.4	1.6	2.25	1.4	V
		$V_O \geq 3.0$	10	3.2	3	4.5	2.9	3.2	4.5	2.9	3.2	4.5	2.9	3.2	4.5	2.9	V
		$V_O \geq 3.5$	5	1.4	1.5	2.25	1.5	1.4	2.25	1.5	1.4	2.25	1.5	1.4	2.25	1.5	V
		$V_O \geq 7.0$	10	2.9	3	4.5	3	2.9	4.5	3	2.9	4.5	3	2.9	4.5	3	V
$I_{DN}$	Output Drive Current N-Channel (Note 2)	0.4	5	3.75	3	4	2.1	3.6	3	3.6	3	2.4	3	2.4	3	2.4	mA
$I_{DP}$	Output Drive Current P-Channel (Note 2)	0.5	10	10	8	10	5.6	9.6	8	9.6	8	6.4	8	6.4	8	6.4	mA
		2.5	5	-1.85	-1.25	-1.75	-0.9	-1.5	-1.25	-1.5	-1.25	-1	-1.25	-1	-1.25	-1	mA
		9.5	10	-0.9	-0.6	-0.8	-0.4	-0.72	-0.6	-0.72	-0.6	-0.48	-0.6	-0.48	-0.48	-0.48	mA
$I_{IN}$	Input Current					10							10				pA

Note 1: This device should not be connected to circuits with the power on because high transient voltage may cause permanent damage.

Note 2:  $I_{DN}$  and  $I_{DP}$  are tested one output at a time.

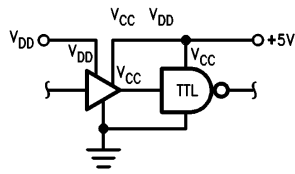
## AC Electrical Characteristics\*

$T_A = 25^{\circ}C$ ,  $C_L = 15$  pF, unless otherwise noted. Typical Temperature coefficient for all values of  $V_{DD} = 0.3\%/^{\circ}C$

Characteristics	Test Conditions	Limits							Units
		CD40XXM			CD40XXC				
		$V_{DD}$ (Volts)	Min	Typ	Max	Min	Typ	Max	
Propagation Delay Time: High-to-Low Level ( $t_{PHL}$ )	$V_{CC} = V_{DD}$	5	—	15	55	—	15	70	ns
	$V_{DD} = 10V$ $V_{CC} = 5V$	10	—	10	30	—	10	40	
Low-to-High Level ( $t_{PLH}$ )	$V_{CC} = V_{DD}$	5	—	50	80	—	50	100	ns
	$V_{DD} = 10V$ $V_{CC} = 5V$	10	—	25	55	—	25	70	
Transition Time: High-to-Low Level ( $t_{THL}$ )	$V_{CC} = V_{DD}$	5	—	20	45	—	20	60	ns
	$V_{CC} = V_{DD}$	10	—	16	40	—	16	50	
Low-to-High Level ( $t_{TLH}$ )	$V_{CC} = V_{DD}$	5	—	80	125	—	80	160	ns
	$V_{CC} = V_{DD}$	10	—	50	100	—	50	120	
Input Capacitance ( $C_i$ )	Any Input		—	5	—	—	5	—	pF

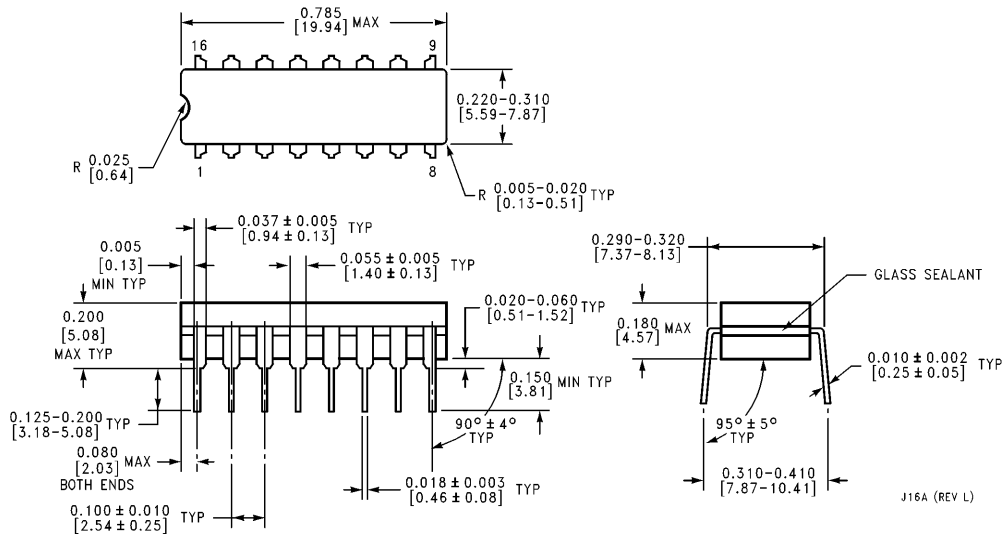
\*AC Parameters are guaranteed by DC correlated testing.

## Typical Application



TL/F/5945-5

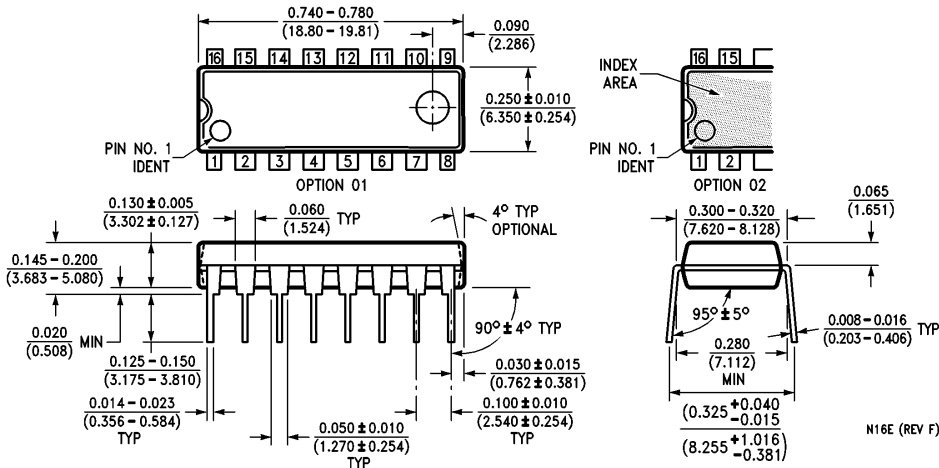
## Physical Dimensions inches (millimeters)



**Ceramic Dual-In-Line Package (J)**  
**Order Number CD4009MJ, CD4009CJ, CD4010MJ or CD4010CJ**  
**NS Package Number J16A**

**CD4009M/CD4009C Hex Buffers (Inverting)  
CD4010M/CD4010C Hex Buffers (Non-Inverting)**

**Physical Dimensions** inches (millimeters) (Continued)



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